

# SHARP

## NEW PRODUCT INFORMATION

### PRELIMINARY

# IR3N74AN

## Compander IC for Cordless Telephone

### ■ Description

The IR3N74AN is a compander IC for noise reduction of wireless telephones.

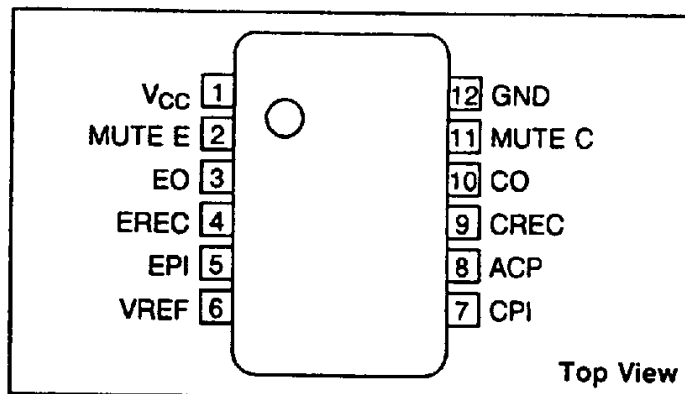
It consists of a compressor whose compressibility is 1/2 in logarithm and an expander whose expandability is 2 in logarithm. This IC ensures clearer speech quality by reducing radio-wave noise which is generated during communications using mobile communication equipment such as cordless telephones and cellular telephones.

In order to comply with the smaller size and lighter weight of those instruments, the IR3N74AN (12-pin SSOP) is offered in a smaller package with less pin count than the previous IR3N74N (16-pin SOP).

### ■ Features

- Amplitude compression and expansion of speech signal  
Compressibility: 1/2 (logarithm),  
Expandability: 2 (logarithm)
- Operation at low voltage,  $V_{CC} = 2.4$  to  $5.5V$  ( $T_a = +25^\circ C$ )
- Low current consumption,  $I_{CC} = 3.4mA$  (TYP.) ( $V_{CC} = 3V$ ,  $T_a = +25^\circ C$ )
- With a compressor input amplifier
- Built-in limiter circuit
- Muting capability
- Package: 12-pin SSOP (SSOP12-P-225)

### ■ Pin Connections



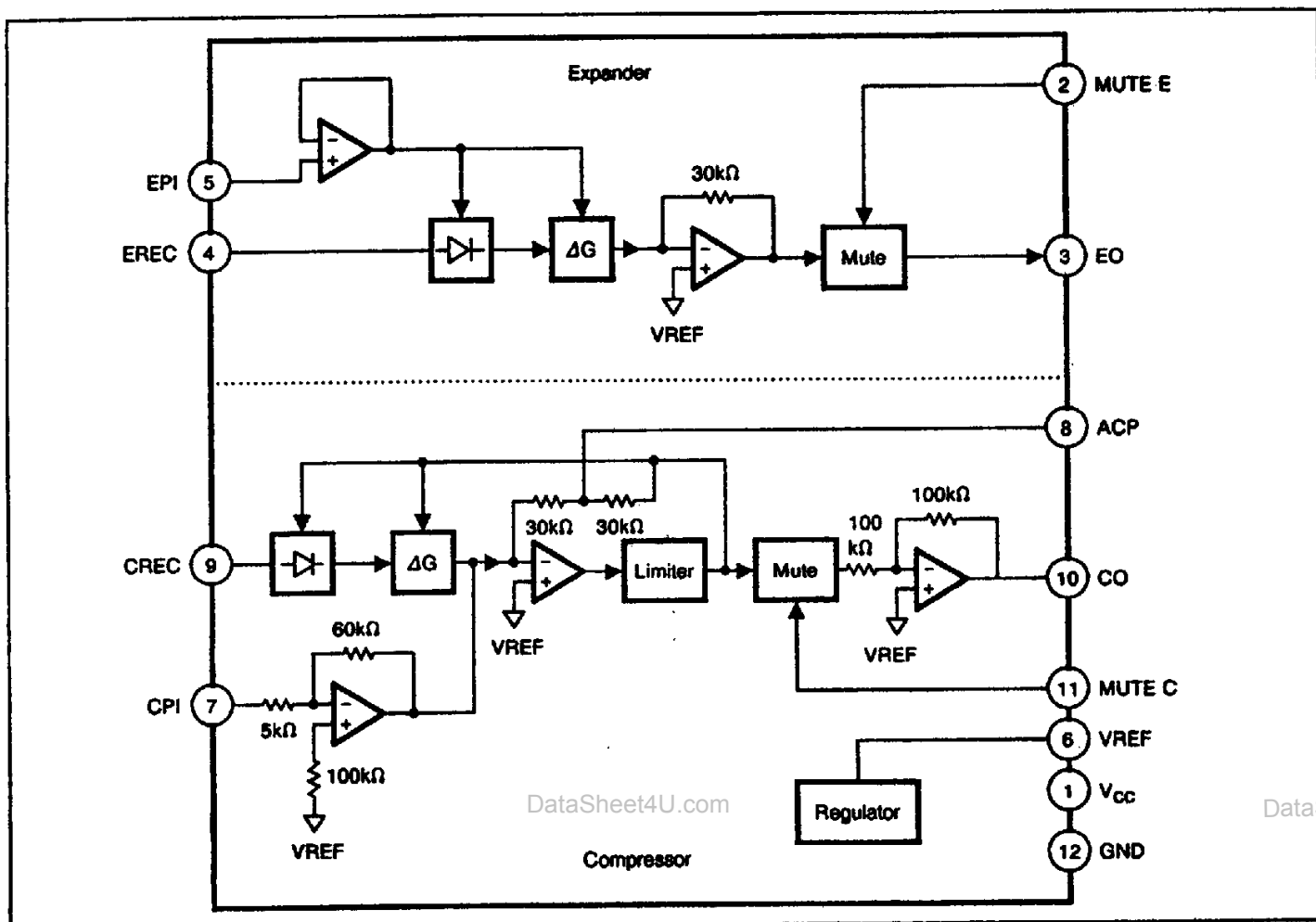
### ■ Pin Description

Symbol	Pin name
$V_{CC}$	Power supply pin
MUTE E	Mute output pin for expander
EO	Expander output pin
EREC	Smoothing capacitor pin for expander
EPI	Expander input pin
VREF	Reference voltage output pin
CPI	Compressor input pin
ACP	Decoupling capacitor pin
CREC	Smoothing capacitor pin for compressor
CO	Compressor output pin
MUTE C	Mute output pin for compressor
GND	Ground pin

# IR3N74AN

## Compander IC for Cordless Telephone

### Block Diagram



### Absolute Maximum Ratings

( $T_a = +25^\circ\text{C}$ )

Parameter	Symbol	Rating	Unit	Note
Supply voltage	$V_{CC}$	6	V	
Mute voltage	$V_{MUTE}$	$V_{CC}$	V	1
Power dissipation	PD	350	mW	2
Operating temperature	$T_{opr}$	-20 to +85	$^\circ\text{C}$	
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$	

Note 1: Applied to pins MUTE E and MUTE C.

Note 2: When  $T_a = +25^\circ\text{C}$ . PD derating ratio is  $3\text{mW}/^\circ\text{C}$ .

### ■ Electrical Characteristics (1)

( $V_{CC} = 3.0V$ ,  $f = 1kHz$ ,  $R_L = 10k\Omega$ ,  $T_a = +25^\circ C$ )

Parameter		Symbol	Test condition	MIN.	TYP.	MAX.	Unit	Note
Operating supply-voltage		$V_{CC}$		2.4		5.5	V	
Current consumption at no signal		$I_{CC}$			3.4	5.3	mA	
Reference pin voltage		$V_{REF}$		1.15	1.25	1.35	V	
Mute switching voltage		$V_{TH}$		1.8		$V_{CC}$	V	
		$V_{TL}$		0		0.8		
Compressor	Reference output voltage	$V_{ROC}$	$V_{IN} = -24.0dBV$	-12.0	-10.0	-8.2	dBV	
	Output deviation	$V_{OC1}$	$V_{IN} = -20.0dB$	-0.6	-0.1	0.4	dB	1
		$V_{OC2}$	$V_{IN} = -40.0dB$	-0.8	-0.2	0.2		
		$V_{OC3}$	$V_{IN} = -60.0dB$		-1.3			
	Distortion	$THD_C$	$V_{IN} = -24.0dBV$		0.4	1.0	%	
	Limiting voltage	$LV_{OC}$	Output distortion: 3%	420	480	540	mV rms	
	Output noise voltage	$V_{NOC}$	$R_g = 600\Omega$		1.5	4.5	mV rms	
	Mute attenuation	$MA_C$	$V_{IN} = -24.0dBV$ Pin No. 11 shall be grounded.	60	80		dB	
	Crosstalk (E→C)	$CT$ (E→C)	Expander input should be $-10.0dBV$ $R_g = 600\Omega$		-40	-30	dB	
	Frequency characteristic	$FRC$	$V_{IN} = -24.0dBV$ $f = 200$ to $5kHz$ $f = 1kHz$ as reference.	-0.5	0	0.5	dB	
DC voltage difference at mute switching	$V_{MOC}$ (OFF→ON)	Voltage at Pin No. 10	-20		20	mV		

# IR3N74AN

## Compander IC for Cordless Telephone

 $(V_{CC} = 3.0V, f = 1kHz, R_L = 10k\Omega, T_a = +25^\circ C)$ 

Parameter		Symbol	Test condition	MIN.	TYP.	MAX.	Unit	Note
Expander	Reference output voltage	$V_{ROE}$	$V_{IN} = -10.0dBV$	-12.0	-10.0	-8.2	dBV	
	Output deviation	$V_{OE1}$	$V_{IN} = -15.0dB$	-0.3	0.2	0.7	dB	2
		$V_{OE2}$	$V_{IN} = -25.0dB$	-0.3	0.2	0.7		
		$V_{OE3}$	$V_{IN} = -35.0dB$	-1.0	0.2	1.0		
	Distortion	$THD_E$	$V_{IN} = -10.0dBV$		0.7	1.5	%	
	Output dynamic range	$DR_{OE}$	Output distortion: 10%	750	900		mV rms	
	Output noise voltage	$V_{NOE}$	$R_g = 600\Omega$		20	40	$\mu V$ rms	
	Mute attenuation	$MA_E$	$V_{IN} = -10.0dBV$ Pin No. 2 shall be grounded.	60	80		dB	
	Crosstalk (C→E)	CT (C→E)	Compressor input should be $-24.0dBV$ $R_g = 600\Omega$		-80	-70	dB	
	Frequency characteristic	$FR_E$	$V_{IN} = -10.0dBV$ $f = 200$ to $5kHz$ $f = 1kHz$ as reference.	-0.5	0	0.5	dB	
DC voltage difference at mute switching	$V_{MOE}$ (OFF→ON)	Voltage at Pin No. 3	-20		20	mV		
Compander	Voltage gain	$V_{ROCE}$	$V_{IN} = -24.0dBV$	11.0	14.0	17.0	dB	
	Distortion	$THD_{CE}$	$V_{IN} = -24.0dBV$		0.5	2.0	%	
	Frequency characteristic	$FR_{CE}$	$V_{IN} = -24.0dBV$ $f = 200$ to $5kHz$ $f = 1kHz$ as reference.	-0.5	0	0.5	dB	

Note 1:  $V_{IN} = 0dB = -24dBV$ , output deviation =  $(V_{OC} - V_{ROC}) - 0.5 \times V_{IN}$  (dB)Note 2:  $V_{IN} = 0dB = -10dBV$ , output deviation =  $(V_{OE} - V_{ROE}) - 2 \times V_{IN}$  (dB)

# IR3N74AN

Companion IC for Cordless Telephone

 $(V_{CC} = 3.0V, f = 1kHz, R_L = 10k\Omega, T_a = -20 \text{ to } +85^\circ C)$ 

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit	Note	
Expander	Reference output voltage	$V_{ROE}$	$V_{IN} = -10.0dBV$	-12.6	-10.0	-7.6	dBV	
	Output deviation	$V_{OE1}$	$V_{IN} = -15.0dBV$	-0.3	0.2	1.0	dB	2
		$V_{OE2}$	$V_{IN} = -25.0dBV$	-0.3	0.2	1.0		
		$V_{OE3}$	$V_{IN} = -35.0dBV$		0.2			
	Distortion	$THD_E$	$V_{IN} = -10.0dBV$		0.7	2.5	%	
	Output dynamic range	$DR_{OE}$	Output distortion: 10%	650	900		mV rms	
	Output noise voltage	$V_{NOE}$	$R_g = 600\Omega$		20	40	$\mu V$ rms	
	Mute attenuation	$MA_E$	$V_{IN} = -10.0dBV$ Pin No. 2 shall be grounded.	60	80		dB	
	Crosstalk (C→E)	CT (C→E)	Compressor input should be $-24.0dBV$ $R_g = 600\Omega$		-80	-60	dB	
	Frequency characteristic	$FR_E$	$V_{IN} = -10.0dBV$ $f = 200 \text{ to } 5kHz$ $f = 1kHz$ as reference.	-0.8	0	0.8	dB	
DC voltage difference at mute switching	$V_{MOE}$ (OFF→ON)	Voltage at Pin No. 3	-30		30	mV		
Companion	Voltage gain	$V_{ROCE}$	$V_{IN} = -24.0dBV$	10.5	14.0	17.5	dB	
	Distortion	$THD_{CE}$	$V_{IN} = -24.0dBV$		0.5		%	
	Frequency characteristic	$FR_{CE}$	$V_{IN} = -24.0dBV$ $f = 200 \text{ to } 5kHz$ $f = 1kHz$ as reference.	-0.8	0	0.8	dB	

Note 1:  $V_{IN} = 0dB = -24dBV$ , output deviation =  $(V_{OC} - V_{ROC}) - 0.5 \times V_{IN}$  (dB)Note 2:  $V_{IN} = 0dB = -10dBV$ , output deviation =  $(V_{OE} - V_{ROE}) - 2 \times V_{IN}$  (dB)

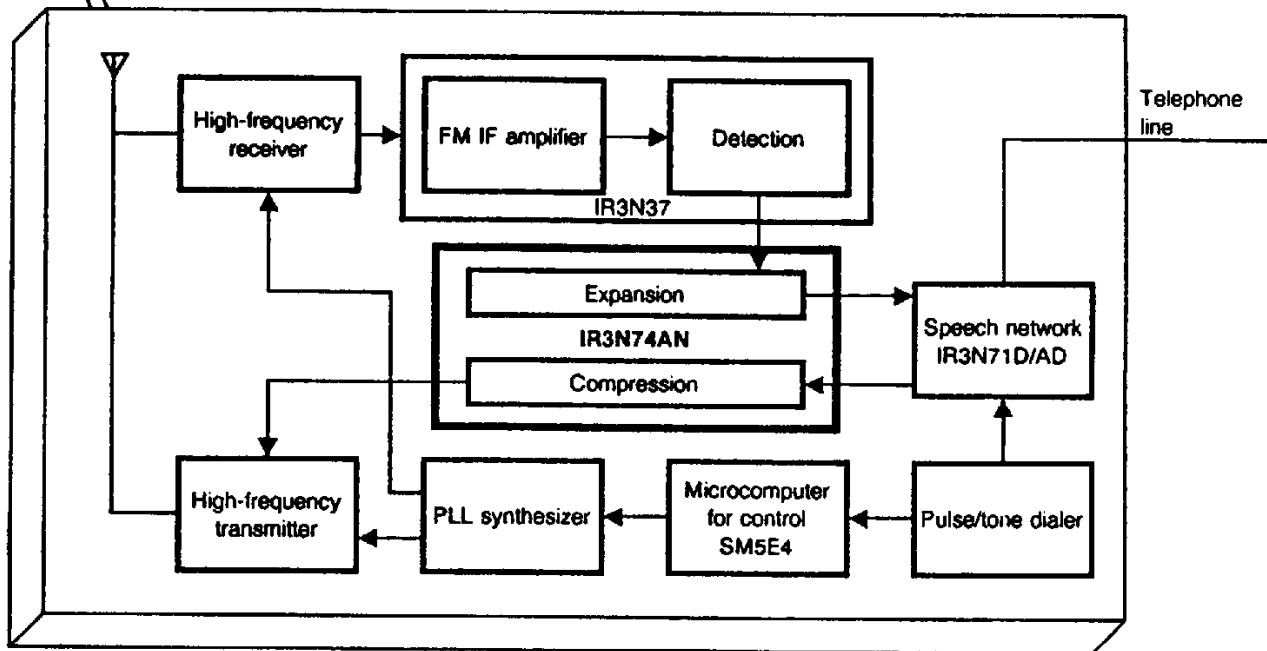
## ■ Electrical Characteristics (2)

( $V_{CC} = 3.0V$ ,  $f = 1kHz$ ,  $R_L = 10k\Omega$ ,  $T_a = -20$  to  $+85^\circ C$ )

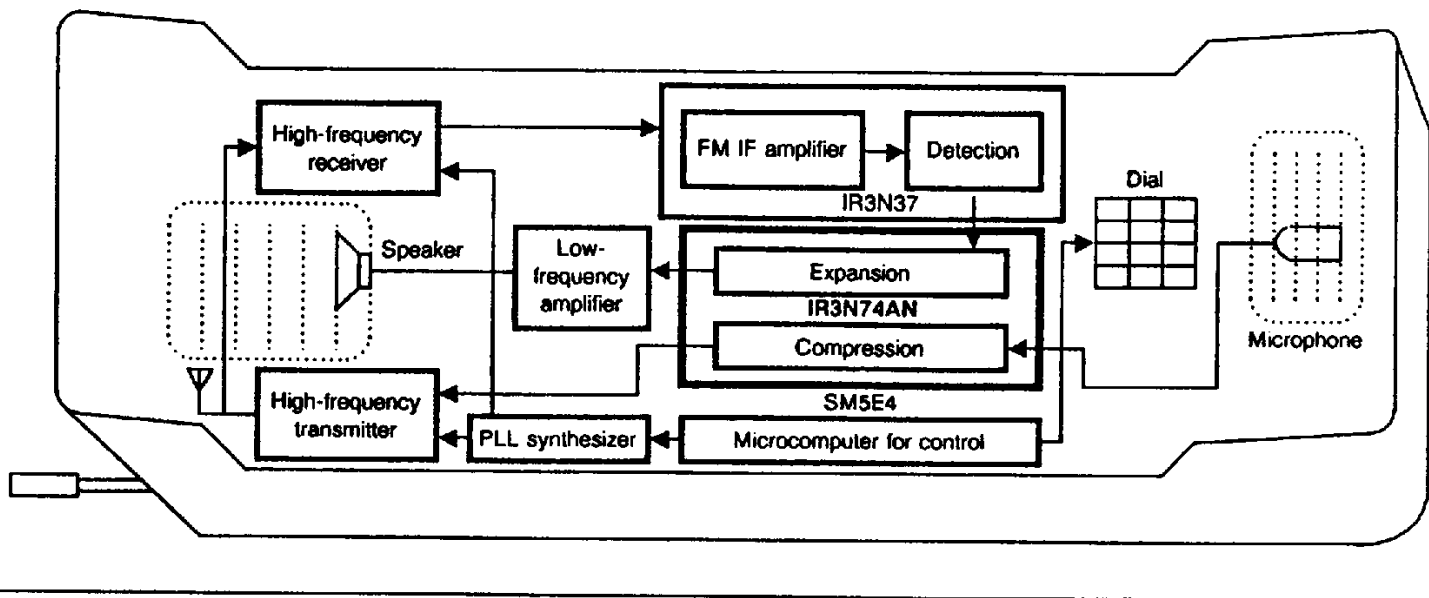
Parameter		Symbol	Test condition	MIN.	TYP.	MAX.	Unit	Note
Operating supply voltage		$V_{CC}$		2.5		5.5	V	
Current consumption at no signal		$I_{CC}$			3.4	5.7	mA	
Reference pin voltage		$V_{REF}$		1.10	1.25	1.40	V	
Mute switching voltage		$V_{TH}$		2.0		$V_{CC}$	V	
		$V_{TL}$		0		0.6		
Compressor	Reference output voltage	$V_{ROC}$	$V_{IN} = -24.0dBV$	-12.6	-10.0	-7.6	dBV	
	Output deviation	$V_{OC1}$	$V_{IN} = -20.0dB$	-0.7	-0.1	0.4	dB	1
		$V_{OC2}$	$V_{IN} = -40.0dB$	-1.2	-0.2	0.2		
		$V_{OC3}$	$V_{IN} = -60.0dB$		-1.3			
	Distortion	$THD_C$	$V_{IN} = -24.0dBV$		0.4		%	
	Limiting voltage	$LV_{OC}$	Output distortion: 3%	380	480	570	mV rms	
	Output noise voltage	$V_{NOC}$	$R_g = 600\Omega$		1.5	4.5	mV rms	
	Mute attenuation	$MA_C$	$V_{IN} = -24.0dBV$ Pin No. 11 shall be grounded.	60	80		dB	
	Crosstalk (E→C)	$CT$ (E→C)	Expander input should be $-10.0dBV$ $R_g = 600\Omega$		-40	-30	dB	
	Frequency characteristic	$FR_C$	$V_{IN} = -24.0dBV$ $f = 200$ to $5kHz$ $f = 1kHz$ as reference.	-0.8	0	0.8	dB	
DC voltage difference at mute switching	$V_{MOC}$ (OFF→ON)	Voltage at Pin No. 10	-30		30	mV		

### System Configuration Example (Cordless Telephone)

Base unit



Portable unit



# IR3N74AN

Companion IC for Cordless Telephone

## ■ Sharp's Product Lineup

Model No.		IR3N74N	IR3N74AN
Package	Type	16SOP	12SSOP
	Pin pitch	1.27mm	0.75mm
Input port	Expander	3 ports	1 port
	Compressor	2 ports	1 port
	Data	1 port	—

## ■ Development Schedule (Target)

Sample ..... Available  
 Mass production start ..... May, '91

The information described herein is intended to introduce descriptions for products that are in development, and specifications and circuitry are subject to change upon final characterization.

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